



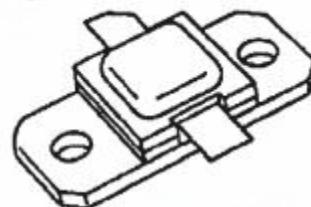
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AM82223-018

RF & MICROWAVE TRANSISTORS TELEMETRY APPLICATIONS

Features

- REFRACTORY/GOLD METALLIZATION
- EMITTER SITE BALLASTED
- ~ 1 VSWR CAPABILITY AT RATED CONDITIONS
- LOW THERMAL RESISTANCE
- INPUT/OUTPUT MATCHING
- OVERLAY GEOMETRY
- METAL/CERAMIC HERMETIC PACKAGE
- $P_{OUT} = 18$ W MINIMUM WITH $G_P = 6.5$ dB GAIN MINIMUM
- COMMON BASE CONFIGURATION



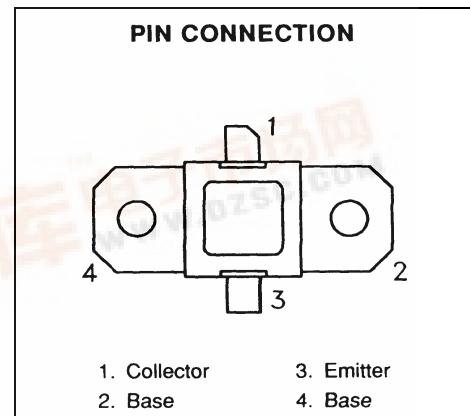
.400 x .400 2L flanged (M214)
hermetically sealed

DESCRIPTION:

The AM82223-018 is a common base, silicon NPN bipolar transistor designed for high gain and efficiency in hi-rel aerospace telemetry applications in the 2.2-2.3 GHz frequency range.

It incorporates internal input and output impedance matching structures along with a rugged, emitter-site ballasted overlay die geometry capable of withstanding ~ 1 load mismatch at any phase angle under full rated operating conditions..

The AM82223-018 is provided in the industry-standard AMPAC™ metal/ceramic hermetic package.



ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

| Symbol | Parameter | Value | Unit |
|-------------------|---------------------------|-------------|------|
| P _{DISS} | Power Dissipation | 58.3 | W |
| I _C | Device Current* | 3.0 | A |
| V _{CC} | Collector-Supply Voltage* | 28 | V |
| T _J | Junction Temperature | 200 | °C |
| T _{STG} | Storage Temperature | -65 to +200 | °C |

Thermal Data

| | | | |
|----------------------|----------------------------------|-----|------|
| R _{TH(J-C)} | Junction-case Thermal Resistance | 3.0 | °C/W |
|----------------------|----------------------------------|-----|------|



AM82223-018

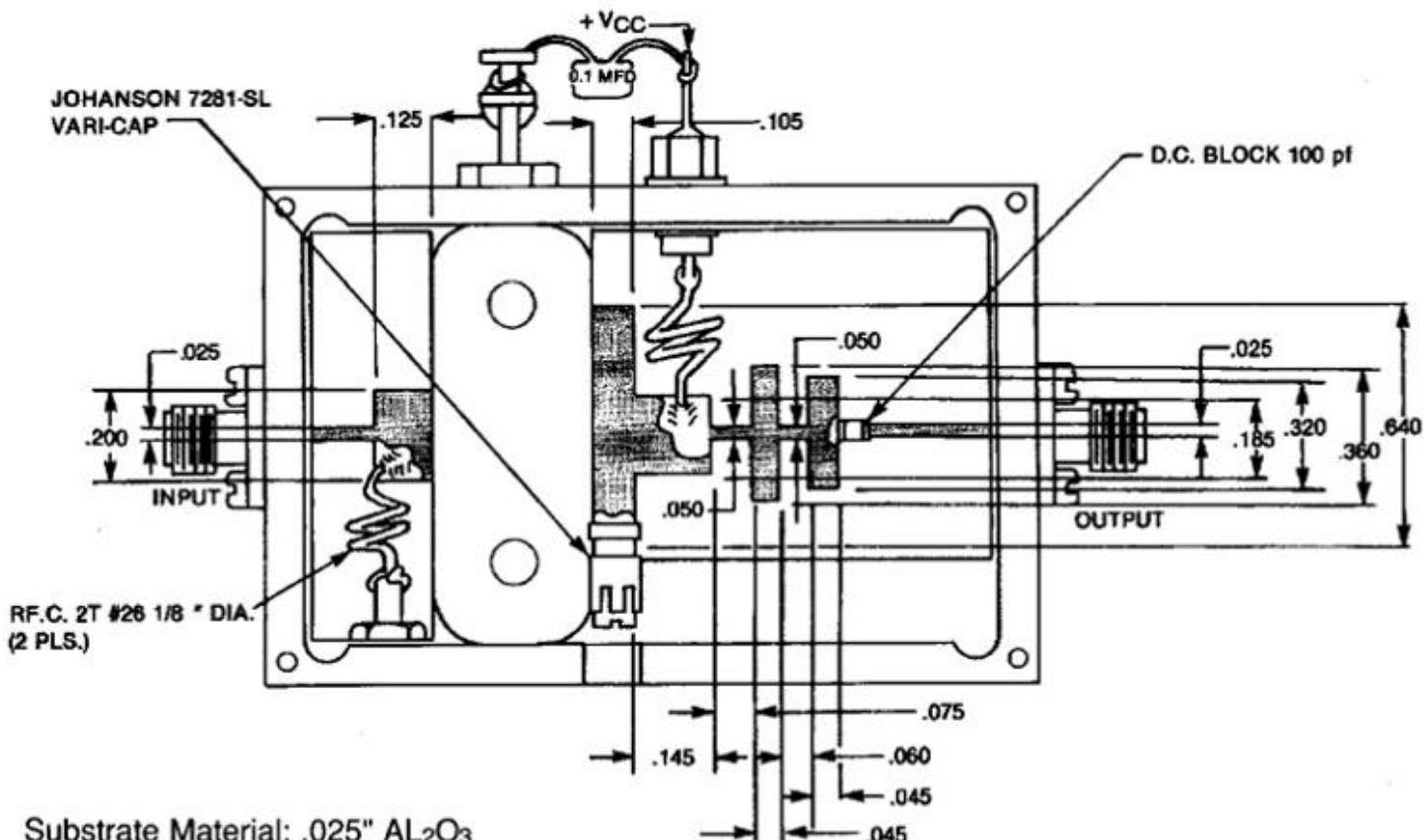
ELECTRICAL SPECIFICATIONS (T_{case} = 25°C)

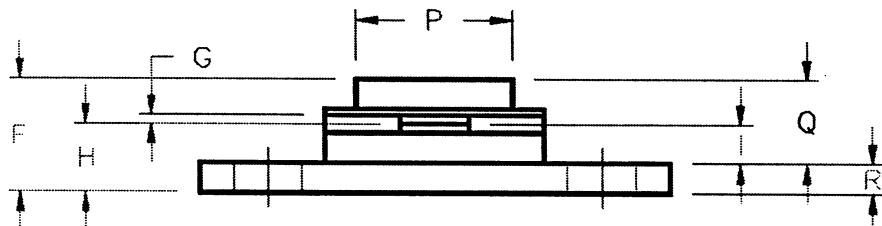
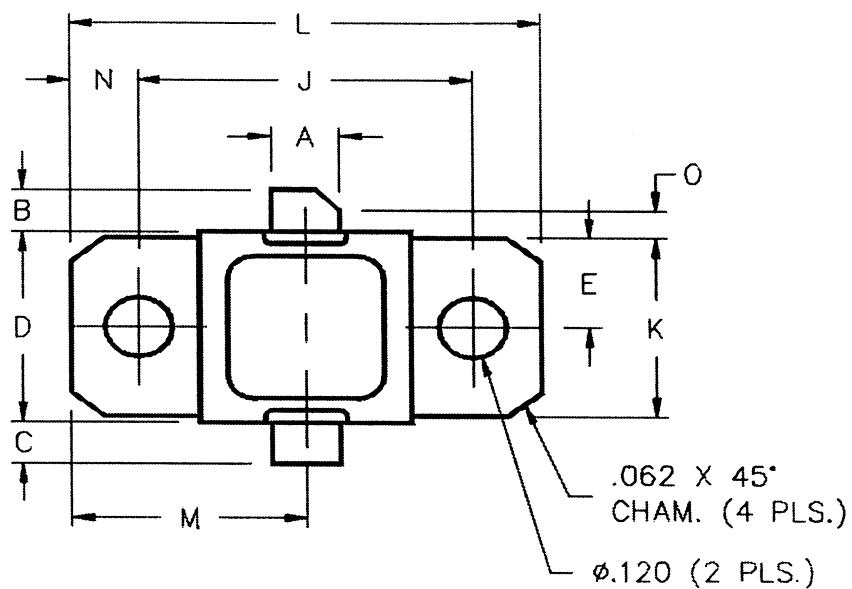
STATIC

| Symbol | Test Conditions | Value | | | Unit |
|------------|--|-------|------|------|------|
| | | Min. | Typ. | Max. | |
| BV_{CBO} | $I_C = 5 \text{ mA}$ $I_E = 0 \text{ mA}$ | 45 | --- | --- | V |
| BV_{EBO} | $I_E = 1 \text{ mA}$ $I_C = 0 \text{ mA}$ | 3.5 | --- | --- | V |
| I_{CBO} | $V_{CB} = 24 \text{ V}$ | --- | --- | 2.0 | mA |
| h_{FE} | $V_{CE} = 5 \text{ V}$ $I_C = 2 \text{ A}$ | 30 | --- | 300 | --- |

DYNAMIC

| Symbol | Test Conditions | Value | | | Unit |
|-----------|--|-------|------|------|------|
| | | Min. | Typ. | Max. | |
| P_{OUT} | $f = 2.2 - 2.3 \text{ GHz}$ $P_{IN} = 4.0 \text{ W}$ $V_{CC} = 24 \text{ V}$ | 18 | --- | --- | W |
| η_C | $f = 2.2 - 2.3 \text{ GHz}$ $P_{IN} = 4.0 \text{ W}$ $V_{CC} = 24 \text{ V}$ | 40 | --- | --- | % |
| G_P | $f = 2.2 - 2.3 \text{ GHz}$ $P_{IN} = 4.0 \text{ W}$ $V_{CC} = 24 \text{ V}$ | 6.5 | --- | --- | dB |

TEST CIRCUIT


PACKAGE MECHANICAL DATA


| | MINIMUM INCHES/MM | MAXIMUM INCHES/MM | | MINIMUM INCHES/MM | MAXIMUM INCHES/MM |
|---|----------------------|----------------------|---|----------------------|----------------------|
| A | .140/3,56 | | J | .650/16,51 | |
| B | .110/2,80 | | K | .386/9,80 | |
| C | .110/2,80 | | L | .900/22,86 | |
| D | .395/10,03 | .407/10,34 | M | .450/11,43 | |
| E | .193/4,90 | | N | .125/3,18 | |
| F | | .230/5,84 | O | .050/1,27 | |
| G | .003/0,08 | .006/0,15 | P | .405/10,29 | |
| H | .118/3,00 | .131/3,33 | Q | .170/4,32 | |
| I | .063/1,60 | | R | .062/1,58 | |